



UTG10N65LND1

Preliminary

Insulated Gate Bipolar Transistor

650V TRENCH GATE FIELD-STOP IGBT

DESCRIPTION

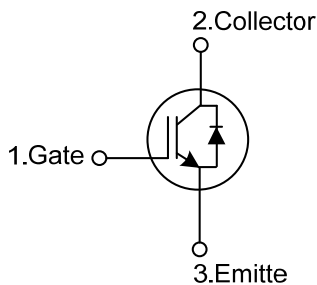
The UTC **UTG10N65LND1** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

The UTC **UTG10N65LND1** is suitable for the resonant or soft switching applications.

FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: $V_{CE(SAT),Typ.}=1.7V @ I_C=10A, V_{GE}=15V$ ($T_C=25^\circ C$)

SYMBOL

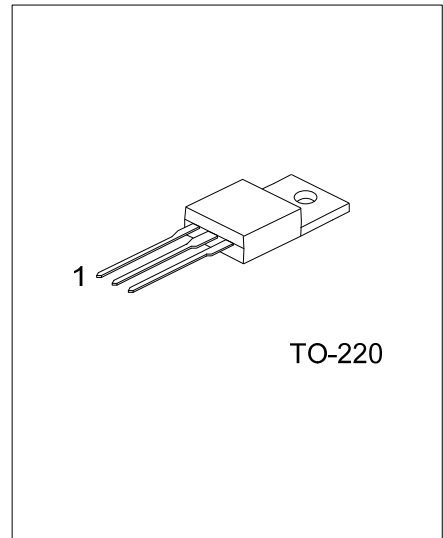


ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UTG10N65LND1L-TA3-T	UTG10N65LND1G-TA3-T	TO-220	G	C	E	Tube

Note: Pin Assignment: G: Gate C: Collector E: Emitter

UTG10N65LND1G-TA3-T 	(1) Packing Type (2) Package Type (3) Green Package	(1) T: Tube (2) TA3: TO-220 (3) G: Halogen Free and Lead Free, L: Lead Free
-------------------------	---	---

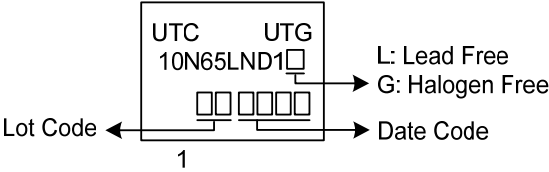


UTG10N65LND1

Preliminary

Insulated Gate Bipolar Transistor

■ MARKING



■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise noted)

PARAMETER	SYMBOL	RATINGS	UNIT	
Collector-Emitter Voltage	V _{CES}	650	V	
Gate-Emitter Voltage	V _{GES}	±20	V	
Transient Gate-emitter voltage (tp < 5 ms)		±25	V	
Continuous Collector Current	I _C	T _C =25°C	20	A
		T _C =100°C	10	A
Collector Current Pulsed (Note 1)	I _{CM}	40	A	
Diode Forward Current	I _F	T _C =25°C	20	A
		T _C =100°C	10	A
Short Circuit Withstand Time V _{GE} = 15V, V _{CC} ≤ 200V Allowed number of short circuits < 1000 Time between short circuits: ≥ 1.0s T _{VJ} = 25°C	t _{SC}	8	μs	
Power Dissipation (T _C =25°C)	P _D	95	W	
Operating Junction Temperature	T _J	-40 ~ +150	°C	
Storage Temperature Range	T _{STG}	-55 ~ +150	°C	

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
 Absolute maximum ratings are those values beyond which the device could be permanently damaged.
 2. Pulse width limited by maximum junction temperature.

■ THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θ _{JC}	1.31	°C/W

■ ELECTRICAL CHARACTERISTICS (T_c=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Off Characteristics							
Collector-Emitter Breakdown Voltage	BV _{CES}		650			V	
Collector Cut-Off Current	I _{CES}	V _{CE} =650V, V _{GE} =0V			5	μA	
G-E Leakage Current	I _{GES}	V _{CE} =0V, V _{GE} =±20V			±400	nA	
On Characteristics							
Gate to Emitter Threshold Voltage	V _{GE(TH)}	I _C =250μA, V _{CE} =V _{GE}	4.5		7.0	V	
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =10A, V _{GE} =15V	T _C =25°C	1.7	2.2	V	
			T _C =125°C	2.0		V	
Dynamic Characteristics							
Input Capacitance	C _{IES}	V _{CE} =25V, V _{GE} =0V, f=1MHz		421		nF	
Output Capacitance	C _{OES}			43		pF	
Reverse Transfer Capacitance	C _{RES}			9		pF	
Switching Characteristics							
Total Gate Charge	Q _G	V _{CE} =520V, I _C =10A, V _{GE} =15V		35		nC	
Gate-Emitter Charge	Q _{GE}			16		nC	
Gate-Collector Charge	Q _{GC}			12		nC	
Turn-On Delay Time	t _{DON)}	V _{CC} =400V, I _C =10A, R _G =5Ω, V _{GE} =0~15V, L=500μH		6		ns	
Rise Time	t _R			15		ns	
Turn-Off Delay Time	t _{DOFF)}			22		ns	
Fall Time	t _F			198		ns	
Turn-On Switching Loss	E _{ON}			0.5		mJ	
Turn-Off Switching Loss	E _{OFF}			0.3		mJ	
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Forward Voltage Drop	V _F		I _F =10A			1.6	V
Reverse Recovery Time	t _{rr}	I _F =10A, di/dt=100A/μS,		58		ns	
Reverse Recovery Charge	Q _{rr}	V _{CC} =400V		190		nC	

■ TEST CIRCUIT AND WAVEFORMS

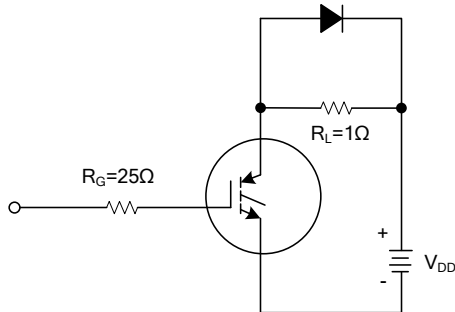


Fig 1. INDUCTIVE SWITCHING TEST CIRCUIT

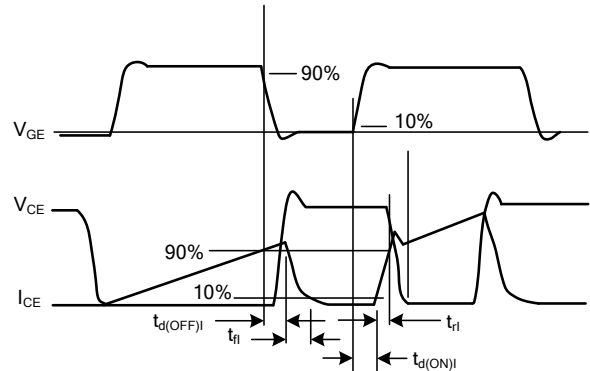


Fig 2. SWITCHING TEST WAVEFORMS

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.